TOSHIBA Transistor Silicon NPN Epitaxial Type

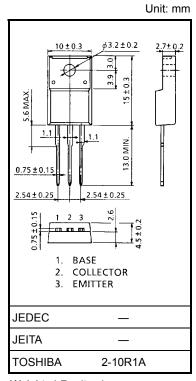
2SC5000

Power Amplifier Applications

• Low collector saturation voltage: VCE (sat) = 0.4 V (max) (IC = 5 A)

Maximum Ratings (Tc = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	80	V
Collector-emitter voltage	V _{CEO}	50	V
Emitter-base voltage	V _{EBO}	7	V
Collector current	Ic	10	А
Base current	Ι _Β	1	А
Collector power dissipation	P _C	25	W
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	-55 to 150	°C

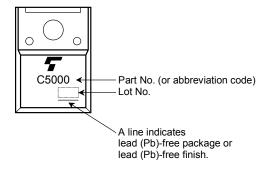


Weight: 1.7 g (typ.)

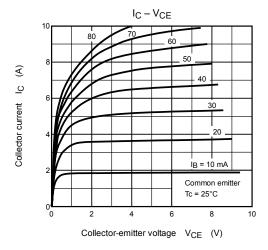
Electrical Characteristics (Tc = 25°C)

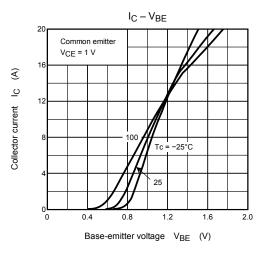
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	V _{CB} = 70 V, I _E = 0	_	_	1	μΑ
Emitter cut-off current		I _{EBO}	V _{EB} = 7 V, I _C = 0	_	_	1	μΑ
Collector-emitter breakdown voltage		V (BR) CEO	I _C = 10 mA, I _B = 0	50	_	_	V
DC current gain		h _{FE (1)}	V _{CE} = 1 V, I _C = 1 A	120	_	400	
Saturation voltage	Collector-emitter	V _{CE (sat)}	I _C = 5 A, I _B = 0.25 A	_	0.19	0.4	V
	Base-emitter	V _{BE (sat)}	I _C = 5 A, I _B = 0.25 A	_	0.96	1.4	
Transition frequency f		f _T	V _{CE} = 1 V, I _C = 1 A	_	90	_	MHz
Collector output capacitance Cob		V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	90	_	pF	

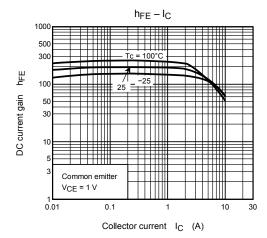
Marking

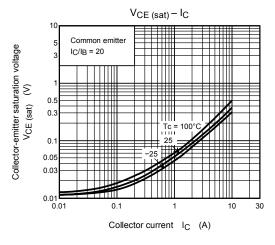


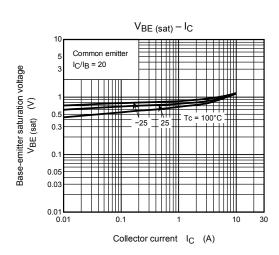
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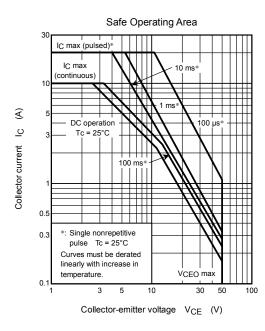












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